NSN 5961-01-176-6659

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-176-6659 **Inclosure Material:** Metal **Overall Length:** 2.400 inches **Overall Height:** 0.500 inches **Overall Width:** 0.750 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 28.0 inflection-point voltage **Current Rating Per Characteristic:** 300.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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